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**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**In re the Application of: **Hitoshi SAOMOTO et al.**Application Number: **10/592,943**Filed: **September 15, 2006**For: **SEMICONDUCTOR LASER ELEMENT AND MANUFACTURING  
METHOD THEREOF**Attorney Docket Number: **062998**Customer Number: **38834****SUPPLEMENTAL INFORMATION DISCLOSURE STATEMENT**Commissioner for Patents  
P. O. Box 1450  
Alexandria, VA 22313-1450

December 7, 2006

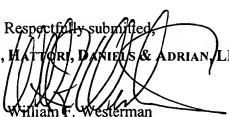
Sir:

In supplement to the Information Disclosure Statement filed September 15, 2006 and in compliance with 37 C.F.R. §1.56, Applicants direct the attention of the Patent and Trademark Office to the documents listed on the attached PTO/SB/08. This paper is being filed within the time periods set forth in 37 C.F.R. §1.97(b).

Cite No. 1 on the attached PTO/SB/08 corrects a typographical error of cited No. 5 on PTO/SB/08, filed on September 15, 2006.

If there are any fees due in connection with the filing of this paper, please charge Deposit Account No. 50-2866.

Respectfully submitted,  
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WFW/yap  
Enclosure: PTO/SB/08



Combined Form PTO/SB-100 (Rev. 10-2004)				Complete if Known	
<b>INFORMATION DISCLOSURE STATEMENT BY APPLICANT</b>  <i>(use as many sheets as necessary)</i>				Application Number	10/592,943
				Confirmation Number	
				Filing Date	September 15, 2006
				First Named Inventor	Hitoshi SAOMOTO et al.
				Art Unit	
				Examiner Name	
Sheet	1	of	1	Attorney Docket Number	062998

U.S. PATENT DOCUMENTS					
Examiner Initials*	Cite No. <sup>1</sup>	Document Number		Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document
		Number	Kind Code <sup>2</sup> (if known)		
		US			
		US			
		US			
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FOREIGN PATENT DOCUMENTS							
Examiner Initials*	Cite No. <sup>1</sup>	Foreign Patent Document			Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Translation <sup>4</sup>
		Country Code <sup>2</sup>	Number <sup>3</sup>	Kind Code <sup>5</sup> (if known)			
/M.C./	1	CA	2304795	A1	04-01-99	Quantum Devices, Inc.	Yes, cited in ISR

NON PATENT LITERATURE DOCUMENTS			
Examiner Initials*	Cite No. <sup>1</sup>	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city, and/or country where published.	Translation <sup>4</sup>

Examiner Signature	/Michael Carter/	Date Considered	02/06/2008
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\*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

<sup>1</sup>Applicant's unique citation designation number (optional). <sup>2</sup>See Kind Codes of USPTO Patent Documents at [www.uspto.gov](http://www.uspto.gov), MPEP 901.04 or in the comment box of this document. <sup>3</sup>Enter Office that issued the document, by the two-letter code (WIPO Standard ST. 3). <sup>4</sup>For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number of the patent document. <sup>5</sup>Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST. 16 if possible. <sup>6</sup>Applicant is to indicate here if English language Translation is attached.